

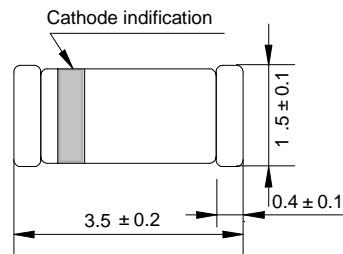
SCHOTTKY BARRIER DIODE
BAS86
FEATURES

- Low forward voltage.
- Guard ring protected.
- Hermetically-sealed leaded glass package.

MECHANICAL DATA

Polarity: Color band denotes cathode

Case: LL-34 glass case



LL-34(SOD-80) Dimensions in millimeters

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Continuous reverse voltage	V_R	50	V
Continuous forward current	I_F	200	mA
Average forward current	$I_{F(AV)}$	200	mA
Repetitive peak forward current	I_{FRM}	500	mA
Non-repetitive peak forward current	I_{FSM}	5	A
Operating ambient temperature	T_{amb}	-65 to +125	$^\circ\text{C}$
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_s	-65 to +150	$^\circ\text{C}$
Thermal resistance from junction to ambient	R_{thja}	320	K/W

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
Forward voltage at $I_F = 0.1\text{mA}$	V_F	-	-	300	mV
at $I_F = 1\text{mA}$	V_F	-	-	380	mV
at $I_F = 10\text{mA}$	V_F	-	-	450	mV
at $I_F = 30\text{mA}$	V_F	-	-	600	mV
at $I_F = 100\text{mA}$	V_F	-	-	90	mV
Reverse current at $V_R = 40\text{V}$	I_R	-	-	5	μA
Reverse recovery time at $I_F = 10\text{mA}, I_R = 10\text{mA}, R_L = 100\Omega$	t_{rr}	-	-	4	ns

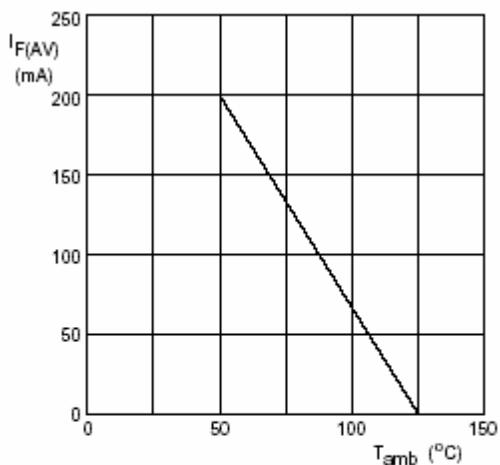
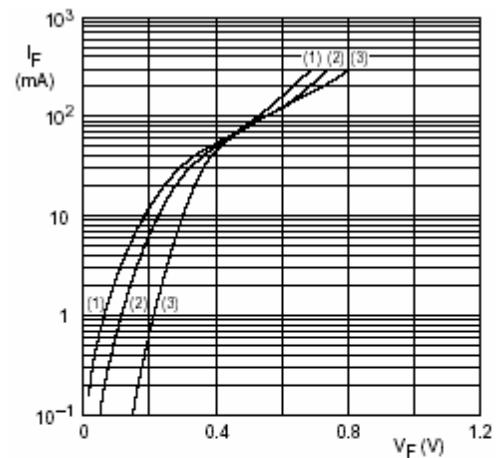
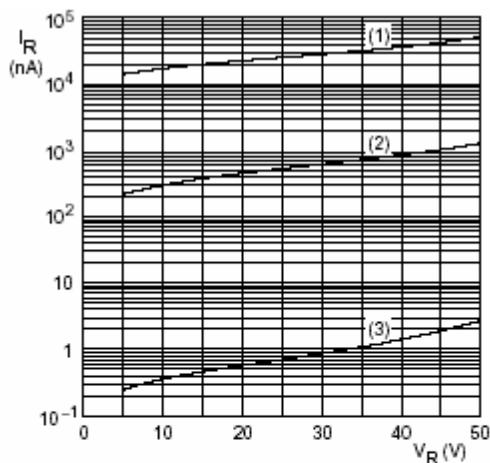
BAS86 Typical Characteristics


Fig.1 Derating curve.



- (1) $T_{amb} = 125^{\circ}\text{C}$.
- (2) $T_{amb} = 85^{\circ}\text{C}$.
- (3) $T_{amb} = 25^{\circ}\text{C}$.

Fig. 2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 85^{\circ}\text{C}$.
- (2) $T_{amb} = 25^{\circ}\text{C}$.
- (3) $T_{amb} = -40^{\circ}\text{C}$.

Fig. 3 Reverse current as a function of reverse voltage; typical values.

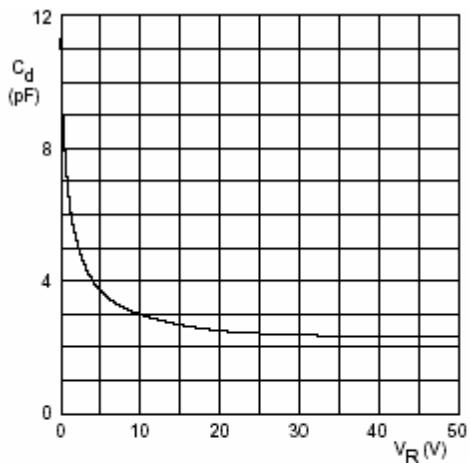

 $f = 1 \text{ MHz}$.

Fig. 4 Diode capacitance as a function of reverse voltage; typical values.